



30V N-Channel NexFET™ Power MOSFET

Check for Samples: CSD17312Q5

FEATURES

- · Optimized for 5V Gate Drive
- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

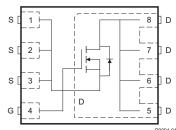
APPLICATIONS

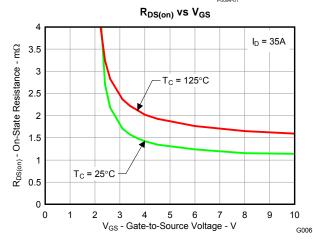
- Notebook Point-of-Load
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.







PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30			
Q_g	Gate Charge Total (4.5V) 28			nC
Q_{gd}	Gate Charge Gate to Drain 6		nC	
		$V_{GS} = 3V$	1.8	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V 1.4		mΩ
		V _{GS} = 8V 1.2		mΩ
V _{GS(th)}	Threshold Voltage 1.1		V	

ORDERING INFORMATION

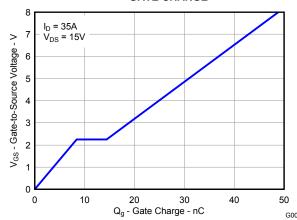
Device	ice Package		Qty	Ship
CSD17312Q5	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	٧
V_{GS}	Gate to Source Voltage	+10 / -8	٧
	Continuous Drain Current, T _C = 25°C	100	Α
I _D	Continuous Drain Current ⁽¹⁾	38	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	200	Α
P_D	Power Dissipation ⁽¹⁾	3.2	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, Single Pulse $I_D = 130A$, $L = 0.1mH$, $R_G = 25\Omega$	845	mJ

- (1) Typical $R_{\theta JA}=39^{\circ} C/W$ when mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%

GATE CHARGE



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN TY	P MAX	UNIT
Static Cl	haracteristics	•			
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30		V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$, $V_{DS} = 24V$		1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$		100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9 1	.1 1.5	V
		$V_{GS} = 3V, I_{D} = 35A$	1.	.8 2.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 35A$	1.	4 1.7	mΩ
		$V_{GS} = 8V, I_D = 35A$	1	.2 1.5	mΩ
9 _{fs}	Transconductance	$V_{DS} = 15V, I_{D} = 35A$	20	0	S
Dynamic	Characteristics				
C _{iss}	Input Capacitance		403	0 5240	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz	222	2890	pF
C _{rss}	Reverse Transfer Capacitance	1 - 11/11/12	9	3 120	pF
R_G	Series Gate Resistance		1.	.1 2.2	Ω
Qg	Gate Charge Total (4.5V)		2	8 36	nC
Q _{gd}	Gate Charge Gate to Drain	V _{DS} = 15V,		6	nC
Q _{gs}	Gate Charge Gate to Source	I _{DS} = 35A	8	.4	nC
Q _{g(th)}	Gate Charge at Vth		4	.4	nC
Q _{oss}	Output Charge	$V_{DS} = 14.8V, V_{GS} = 0V$	5	57	nC
t _{d(on)}	Turn On Delay Time		9	.5	ns
t _r	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V,	2	27	ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 35A$, $R_G = 2\Omega$	3	15	ns
t _f	Fall Time		2	23	ns
Diode Cl	haracteristics				•
V _{SD}	Diode Forward Voltage	I _{SD} = 35A, V _{GS} = 0V	0	.8 1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = 14.8V, I _F = 35A,	8	88	nC
t _{rr}	Reverse Recovery Time	di/dt = 300A/μs	4	3	ns
	1	1			

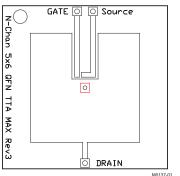
THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

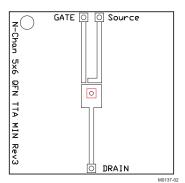
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case (1)			1	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			49	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.





Max $R_{\theta JA} = 49^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 119^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

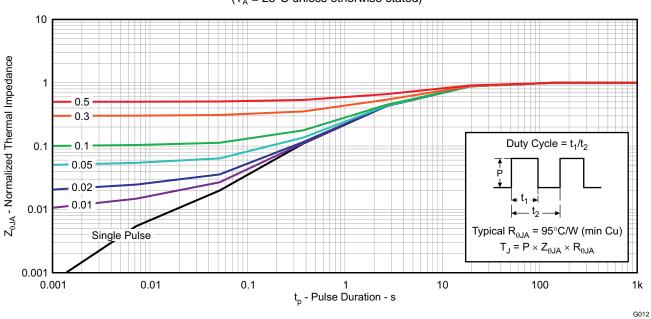


Figure 1. Transient Thermal Impedance

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

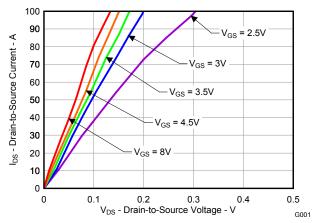


Figure 2. Saturation Characteristics

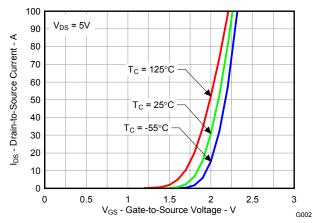


Figure 3. Transfer Characteristics

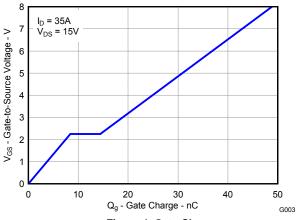


Figure 4. Gate Charge

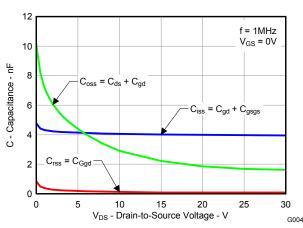


Figure 5. Capacitance

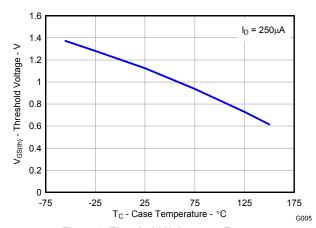


Figure 6. Threshold Voltage vs. Temperature

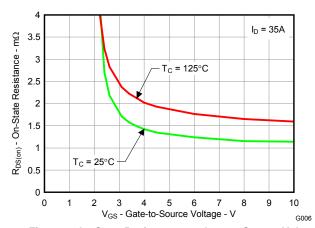


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

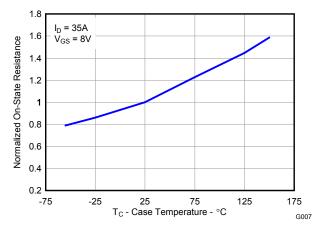


Figure 8. Normalized On-State Resistance vs. Temperature

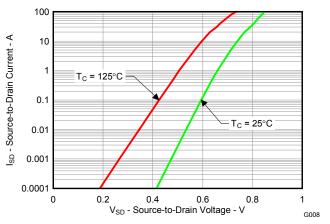


Figure 9. Typical Diode Forward Voltage

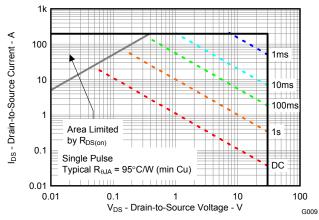


Figure 10. Maximum Safe Operating Area

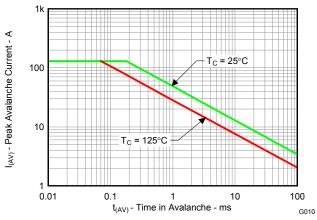


Figure 11. Single Pulse Unclamped Inductive Switching

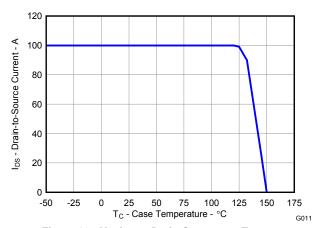
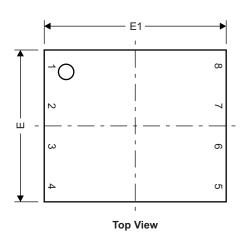


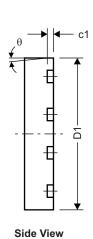
Figure 12. Maximum Drain Current vs. Temperature

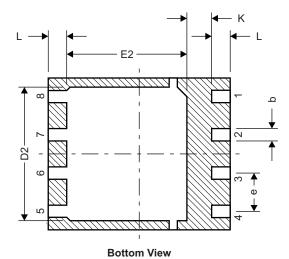


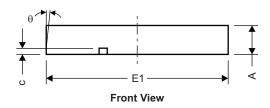
MECHANICAL DATA

Q5 Package Dimensions







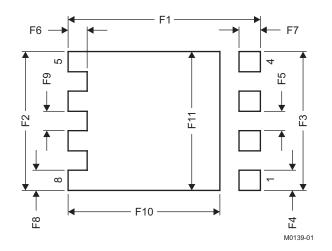


M0140-01

DIM	MILLIM	ETERS	INCHES		
DIW	MIN	MAX	MIN	MAX	
Α	0.950	1.050	0.037	0.039	
b	0.360	0.460	0.014	0.018	
С	0.150	0.250	0.006	0.010	
c1	0.150	0.250	0.006	0.010	
D1	4.900	5.100	0.193	0.201	
D2	4.320	4.520	0.170	0.178	
E	4.900	5.100	0.193	0.201	
E1	5.900	6.100	0.232	0.240	
E2	3.920	4.12	0.154	0.162	
е	1.27	TYP	0.0	050	
K	0.760		0.030		
L	0.510	0.710	0.020	0.028	
θ	0.00				



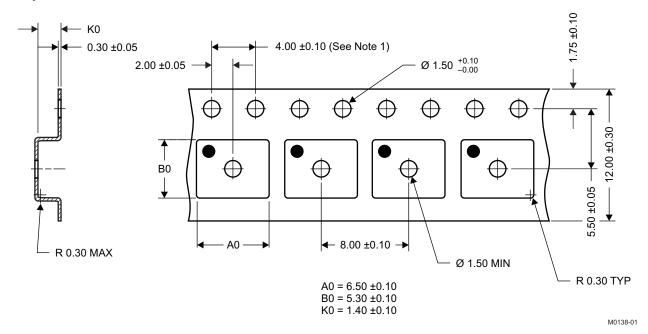
Recommended PCB Pattern



DIM	MILLIM	ETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5 Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and convection) PbF reflow compatible



REVISION HISTORY

Cł	hanges from Original (March 2010) to Revision A	Page
•	Deleted the Package Marking Information section	

PACKAGE MATERIALS INFORMATION

www.ti.com 4-Feb-2011

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17312Q5	SON	DQH	8	2500	330.0	12.8	6.5	5.3	1.4	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 4-Feb-2011



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD17312Q5	SON	DQH	8	2500	335.0	335.0	32.0

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